

NJL3281D (NPN) NJL1302D (PNP)

Complementary ThermalTrak™ Transistors

The ThermalTrak family of devices has been designed to eliminate thermal equilibrium lag time and bias trimming in audio amplifier applications. They can also be used in other applications as transistor die protection devices.

Features

- Thermally Matched Bias Diode
- Instant Thermal Bias Tracking
- Absolute Thermal Integrity
- High Safe Operating Area

Benefits

- Eliminates Thermal Equilibrium Lag Time and Bias Trimming
- Superior Sound Quality Through Improved Dynamic Temperature Response
- Significantly Improved Bias Stability
- Simplified Assembly
 - ◆ Reduced Labor Costs
 - ◆ Reduced Component Count
- High Reliability

Applications

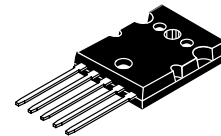
- High-End Consumer Audio Products
 - ◆ Home Amplifiers
 - ◆ Home Receivers
- Professional Audio Amplifiers
 - ◆ Theater and Stadium Sound Systems
 - ◆ Public Address Systems (PAs)



ON Semiconductor®

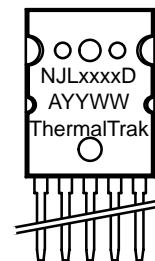
<http://onsemi.com>

**BIPOLAR POWER
TRANSISTORS
15 A, 260 V, 200 W**

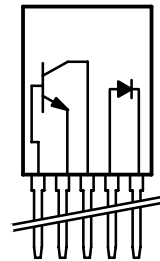


TO-264, 5 LEAD
CASE 340AA
STYLE 1

MARKING DIAGRAM



SCHEMATIC



xxxx = Specific Device Code
A = Assembly Location
YY = Year
WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

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MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	260	Vdc
Collector–Base Voltage	V _{CBO}	260	Vdc
Emitter–Base Voltage	V _{EBO}	5	Vdc
Collector–Emitter Voltage – 1.5 V	V _{CEX}	260	Vdc
Collector Current	I _C	15 25	Adc
			– Continuous – Peak (Note 1)
Base Current – Continuous	I _B	1.5	Adc
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	200 1.43	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	– 65 to +150	°C
DC Blocking Voltage	V _R	200	V
Average Rectified Forward Current	I _{F(AV)}	1.0	A

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction–to–Case	R _{θJC}	0.625	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

ATTRIBUTES

Characteristic	Value
ESD Protection	Human Body Model Machine Model
	>8000 V > 400 V
Flammability Rating	UL 94 V–0 @ 0.125 in

ORDERING INFORMATION

Device	Package	Shipping
NJL3281D	TO–264	25 Units / Rail
NJL1302D	TO–264	25 Units / Rail

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (I _C = 100 mAdc, I _B = 0)	V _{CEO(sus)}	260	–	Vdc
Collector Cutoff Current (V _{CB} = 260 Vdc, I _E = 0)	I _{CBO}	–	50	μAdc
Emitter Cutoff Current (V _{EB} = 5 Vdc, I _C = 0)	I _{EBO}	–	5	μAdc
ON CHARACTERISTICS				
DC Current Gain (I _C = 500 mAdc, V _{CE} = 5 Vdc) (I _C = 1 Adc, V _{CE} = 5 Vdc) (I _C = 3 Adc, V _{CE} = 5 Vdc) (I _C = 5 Adc, V _{CE} = 5 Vdc) (I _C = 8 Adc, V _{CE} = 5 Vdc)	h _{FE}	75 75 75 75 45	150 150 150 150 –	
Collector–Emitter Saturation Voltage (I _C = 10 Adc, I _B = 1 Adc)	V _{CE(sat)}	–	3	Vdc
DYNAMIC CHARACTERISTICS				
Current–Gain – Bandwidth Product (I _C = 1 Adc, V _{CE} = 5 Vdc, f _{test} = 1 MHz)	f _T	30	–	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	–	600	pF
Maximum Instantaneous Forward Voltage (Note 2) (i _F = 1.0 A, T _J = 25°C) (i _F = 1.0 A, T _J = 150°C)	V _F		1.1 0.93	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, T _J = 25°C) (Rated dc Voltage, T _J = 150°C)	i _R		10 100	μA
Maximum Reverse Recovery Time (i _F = 1.0 A, di/dt = 50 A/μs)	t _{rr}		100	ns

2. Diode Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

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TYPICAL CHARACTERISTICS

PNP NJL1302D

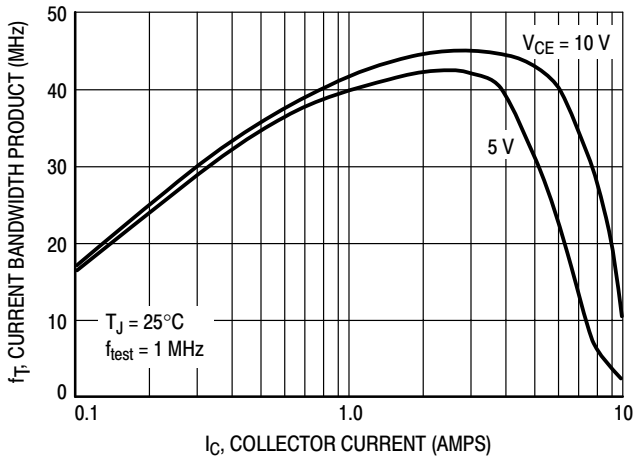


Figure 1. Typical Current Gain Bandwidth Product

NPN NJL3281D

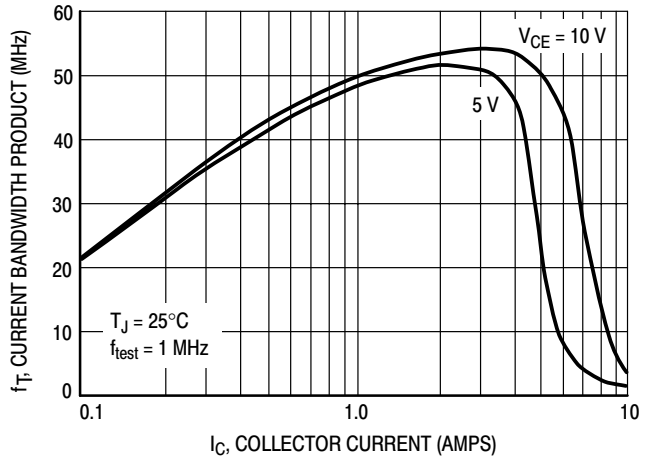


Figure 2. Typical Current Gain Bandwidth Product

PNP NJL1302D

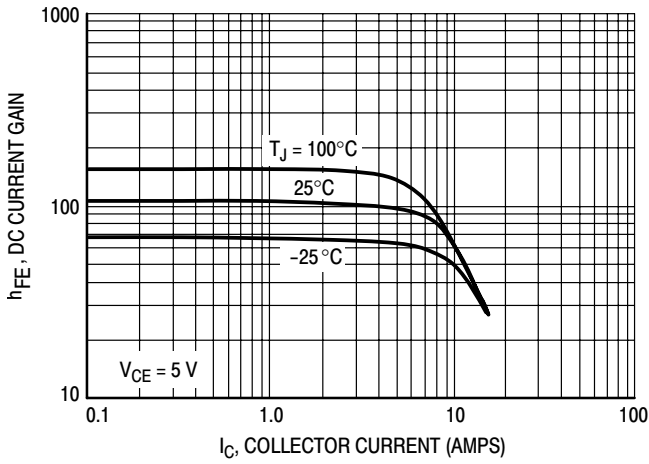


Figure 3. DC Current Gain, $V_{CE} = 5V$

NPN NJL3281D

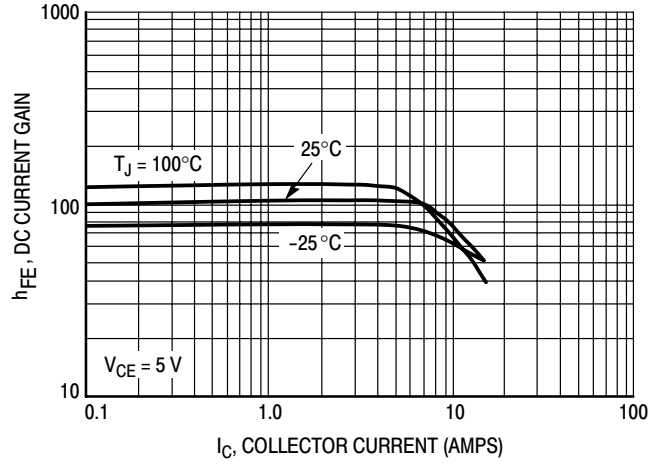


Figure 4. DC Current Gain, $V_{CE} = 5V$

PNP NJL1302D

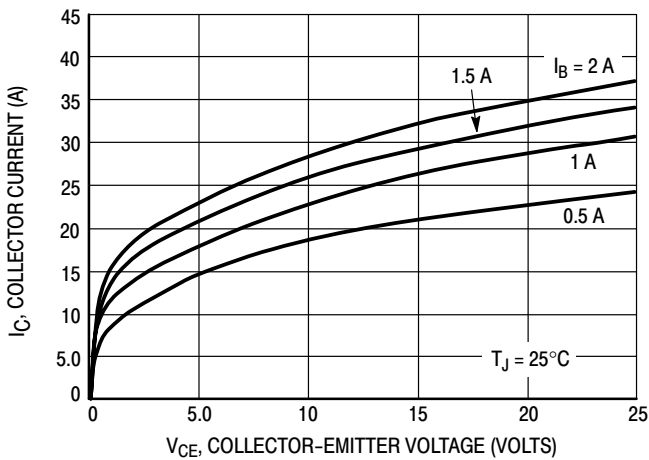


Figure 5. Typical Output Characteristics

NPN NJL3281D

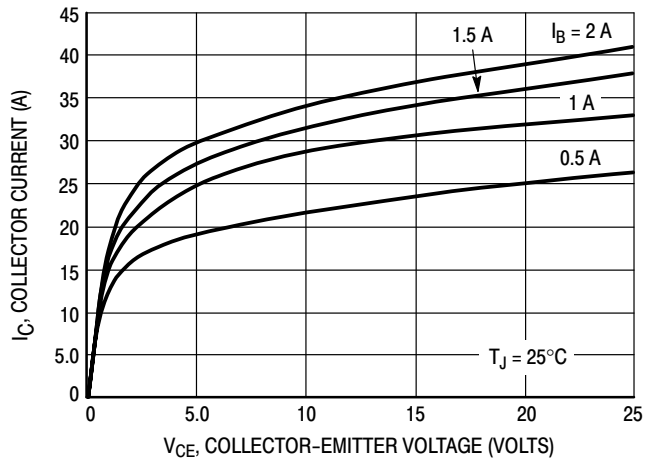


Figure 6. Typical Output Characteristics

NJL3281D (NPN) NJL1302D (PNP)

TYPICAL CHARACTERISTICS

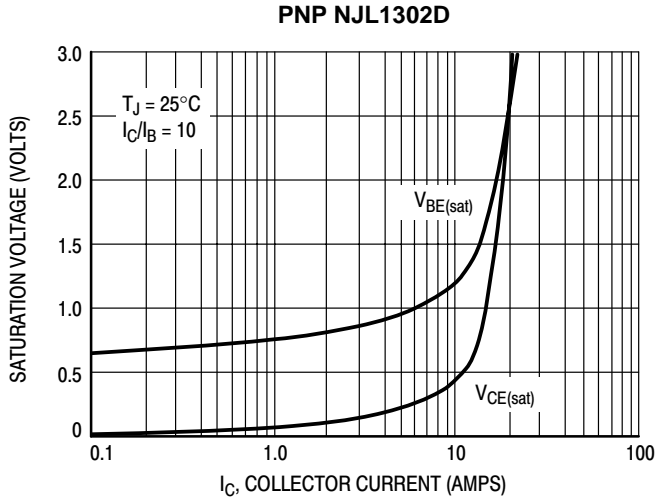


Figure 7. Typical Saturation Voltages

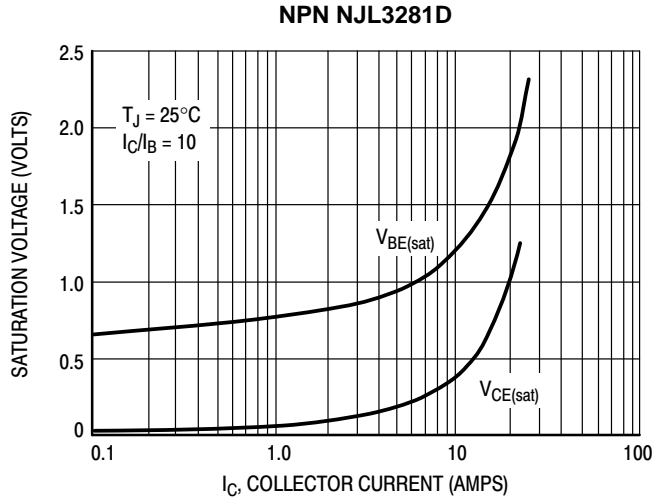


Figure 8. Typical Saturation Voltages

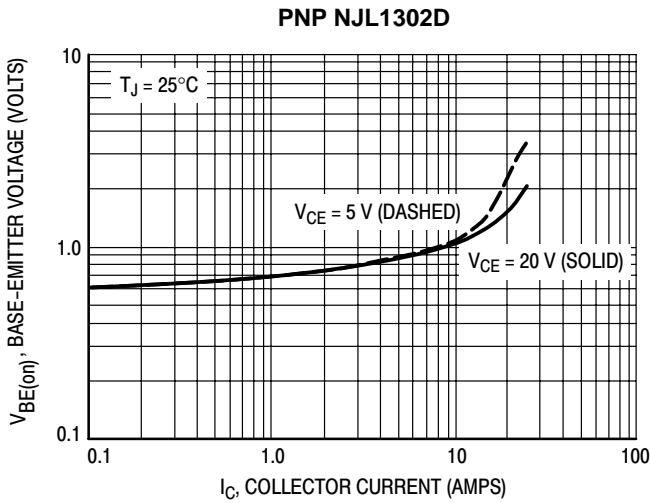


Figure 9. Typical Base-Emitter Voltage

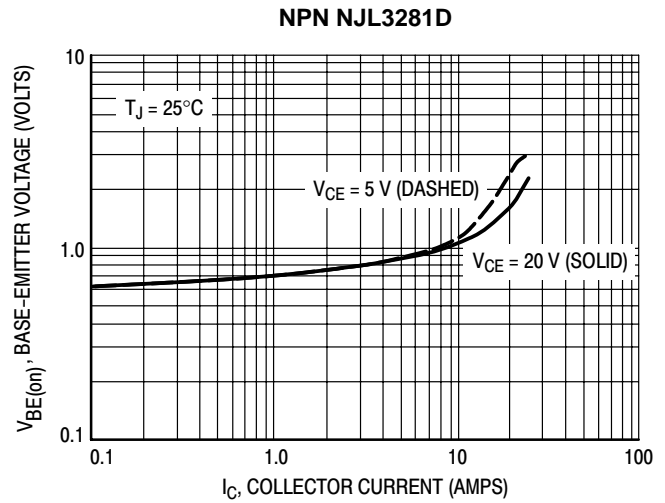


Figure 10. Typical Base-Emitter Voltage

NJL3281D (NPN) NJL1302D (PNP)

TYPICAL CHARACTERISTICS

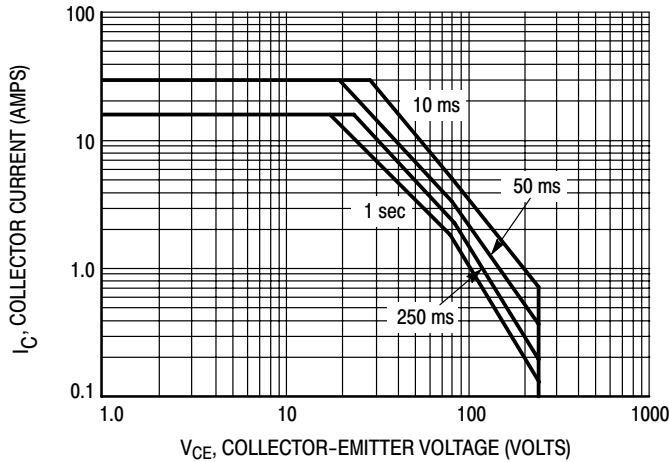


Figure 11. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 11 is based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

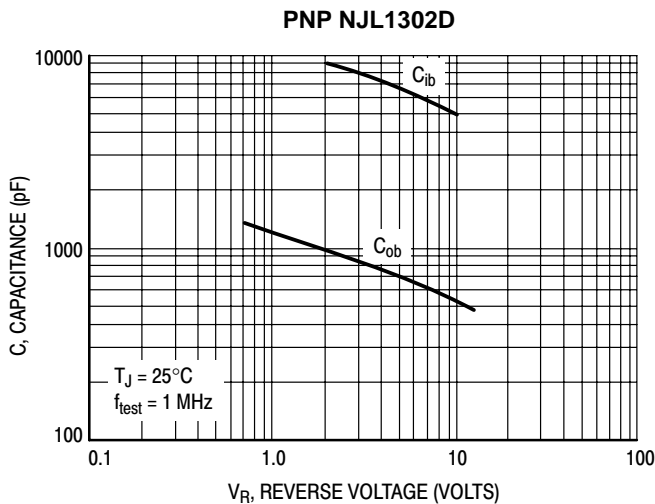


Figure 12. NJL1302D Typical Capacitance

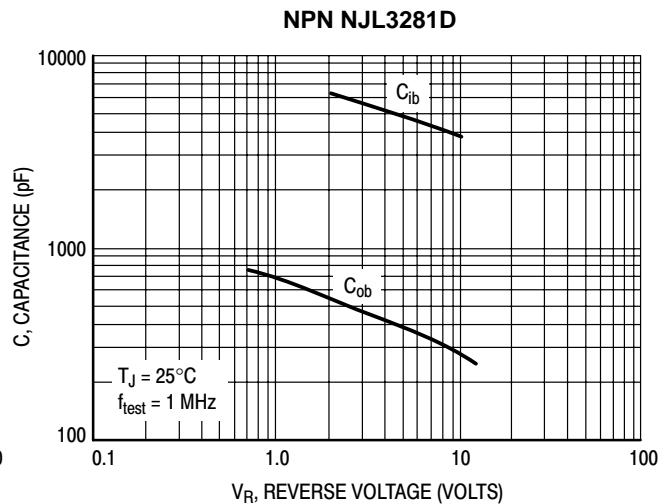


Figure 13. NJL3281D Typical Capacitance

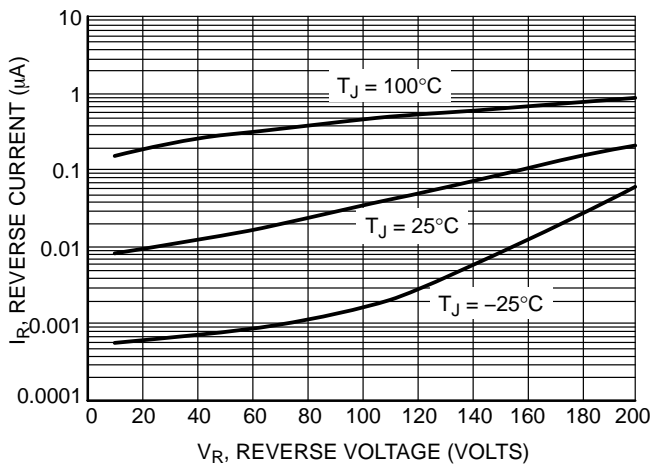


Figure 14. Typical Reverse Current

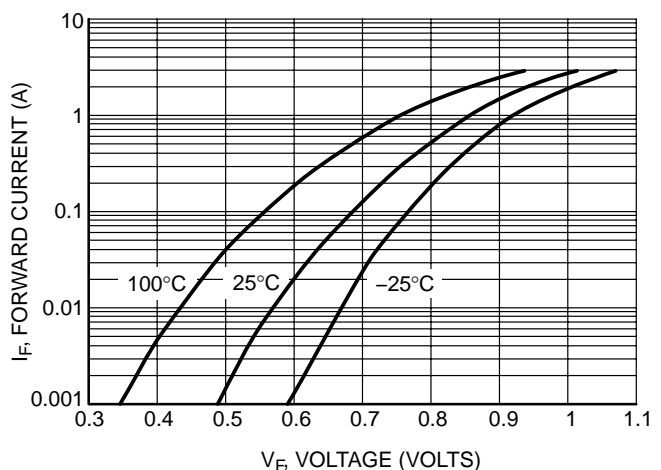
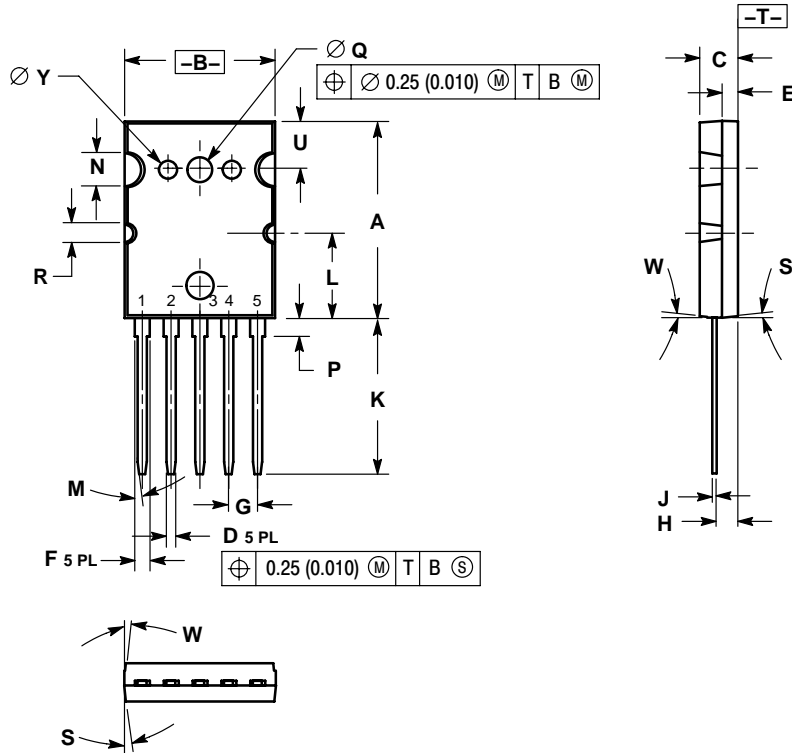


Figure 15. Typical Forward Voltage

NJL3281D (NPN) NJL1302D (PNP)

PACKAGE DIMENSIONS

TO-264, 5 LEAD
CASE 340AA-01
ISSUE O




- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	25.857	25.984	26.111	1.018	1.023	1.028
B	19.761	19.888	20.015	0.778	0.783	0.788
C	4.928	5.055	5.182	0.194	0.199	0.204
D	1.219 BSC			0.0480 BSC		
E	2.032	2.108	2.184	0.0800	0.0830	0.0860
F	1.981 BSC			0.0780 BSC		
G	3.81 BSC			0.150 BSC		
H	2.667	2.718	2.769	0.1050	0.1070	0.1090
J	0.584 BSC			0.0230 BSC		
K	20.422	20.549	20.676	0.804	0.809	0.814
L	11.28 REF			0.444 REF		
M	0°	---	7°	0°	---	7°
N	4.57 REF			0.180 REF		
P	2.259	2.386	2.513	0.0889	0.0939	0.0989
Q	3.480 BSC			0.1370 BSC		
R	2.54 REF			0.100 REF		
S	0°	---	8°	0°	---	8°
U	6.17 REF			0.243 REF		
W	0°	---	6°	0°	---	6°
Y	2.388 BSC			0.0940 BSC		

- STYLE 1:
PIN 1. BASE
2. EMITTER
3. COLLECTOR
4. ANODE
5. CATHODE

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